

SANYO Semiconductors DATA SHEET

LA6574H —

Monolithic Linear IC

Five-Channel Driver (four BTL channels plus one H bridge channel) for MD and CD Player

Overview

The LA6574H is a motor driver IC for MD and CD players with four BTL channels and one H bridge channel. The LA6574H features a separate power supply for the H bridge block, an output adjustment pin, and a 3.3 V regulator to support a wide range of applications.

Functions and Features

- · Four power amplifier channels plus one H bridge channel
- I_O max: 700 mA (each channel)
- Built-in level shifting circuits for the BLT amplifiers
- Thermal protection circuit (Thermal shutdown circuit)
- · Separate loading block power supply
- Built-in 3.3 V regulator
- Provides a dedicated pin for adjusting the loading block output.

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC} max		14	V
Allowable newer dissipation	Pdmax	Independent IC	0.82	W
Allowable power dissipation	Pulliax	* Mounted on a board.	2.0	W
Maximum output current	I _O max	Each channel for CH1 to CH5	0.7	Α
Maximum input voltage	VINB		13	V
MUTE pin voltage	VMUTE		13	V
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

Note *: Mounted on a board (76.1 × 114.3 × 1.6 mm) Material: glass epoxy

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		5.6 to 13	V

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LA6574H

Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{CC}1 = V_{CC}2 = 8~V$, VREF = 1.65~V

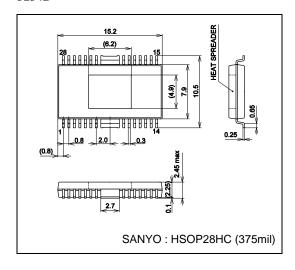
Parameter	Symbol	Conditions	Ratings			Unit	
Farameter	Symbol	Conditions	min	typ	max	Offic	
[Overall Characteristics]							
No load current drain - ICC on	load current drain - ICC on I _{CC} -ON All outputs on, FWD = REV = 0 V *1			30	50	mA	
VREF input voltage range	VREF-IN		1		V _{CC} -1.5	V	
[BTL Amplifier Block]							
Output offset voltage	VOFF	BTL amplifiers, the voltage difference across each channel's output	-50		+50	mV	
Input voltage range	V _{IN}	Input resistance: 11 kΩ	0		Vcc	V	
Output voltage	Vo	The voltage between each of the V _O +/V _O – pairs when R _L is 8 Ω . *2	4	5		V	
Closed loop voltage gain	VG	Gain from input to output		4		Multi- plier	
Slew rate	SR	With the amplifier operating independently, twice the value measured between outputs *4		0.5		V/μs	
[H Bridge Block]	•						
Output voltage	V _O -LOAD	The voltage between each of the V_{O} +/ V_{O} - pairs when R _L is 8 Ω . *2		6		٧	
Low-level input voltage	V _{IN} -L				1	V	
High-level input voltage	V _{IN} -H		2			V	
Output control voltage	VCONT	VCONT = 3 V *2		3.5		V	
[Regulator Block]							
Output voltage	Vreg	I _L = 100 mA	3.05	3.3	3.55	V	
Load regulation	ΔVRL	I _L = 0 to 200 mA	-50	0	+10	mV	
Line regulation	ΔVVCC	V _{CC} = 6 to 12 V, I _L = 100 mA	-15	+21	+60	mV	

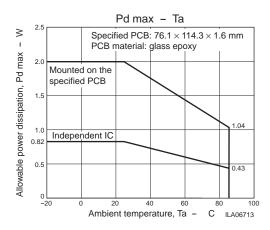
Note *1: The total current drain for $V_{\mbox{\footnotesize{CC}}}1$ and $V_{\mbox{\footnotesize{CC}}}2$ with no load.

- *2: Voltage difference across the load (8 Ω). With the outputs in the saturated state.
- *3: When the MUTE pin is high, the outputs will be on, and when low, the outputs will be off (high-impedance state).
- *4: Design guarantee value

Package Dimensions

unit: mm 3234B





LA6574H

Pin Functions

Pin No.	Symbol	Pin descriptions
1	V _{CC} 2	Channels 3, 4, and 5 power supply (This pin must be shorted to V _{CC} 1 and V _{CC} -S.)
2	V _O 5-	Loading output (-)
3	V _O 5+	Loading output (+)
4	V _O 4+	Channel 4 output (+)
5	V _O 4-	Channel 4 output (-)
6	V _O 3+	Channel 3 output (+)
7	V _O 3–	Channel 3 output (-)
8	V _O 2+	Channel 2 output (+)
9	V _O 2-	Channel 2 output (-)
10	V _O 1+	Channel 1 output (+)
11	V _O 1-	Channel 1 output (-)
12	V _{CC} 1	Channels 1 and 2 (BTL) power supply (This pin must be shorted to V _{CC} -S and V _{CC} 2.)
13	V _{IN} 1	Channel 1 input
14	V _{IN} 1G	Channel 1 input (gain adjustment input)
15	V _{IN} 2	Channel 2 input
16	V _{IN} 2G	Channel 2 input (gain adjustment input)
17	V _{IN} 3	Channel 3 input
18	V _{IN} 3G	Channel 3 input (gain adjustment input)
19	REG-IN	Regulator input (external pnp transistor base)
20	REG-OUT	Regulator output (external pnp transistor collector)
21	VREF-IN	Reference voltage input
22	V _{CC} -S	Signal system power supply (This pin must be shorted to V _{CC} 1 and V _{CC} 2.)
23	V _{IN} 4G	Channel 4 input (gain adjustment input)
24	V _{IN} 4	Channel 4 input
25	VCONT	Channel 5 (VLO) output voltage control
26	S-GND	Signal system ground
27	FWD	Channel 5 (VLO) output switching (FWD); loading block logic input
28	REV	Channel 5 (VLO) output switching (REV); loading block logic input

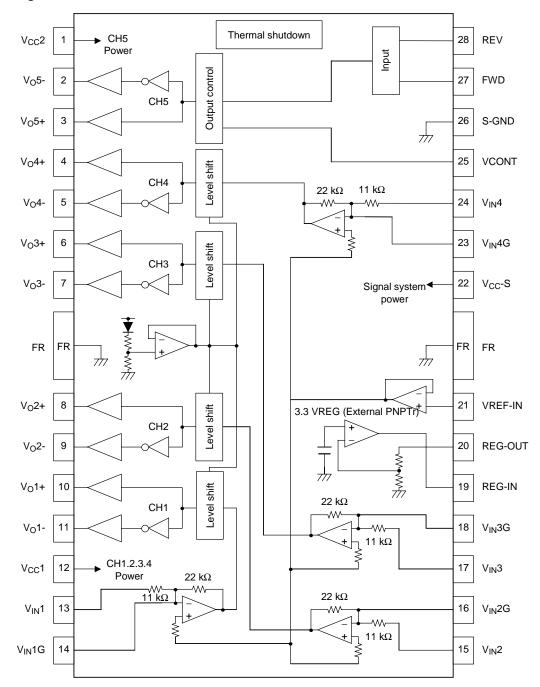
Note: • The center frame (FR) is used as the power system ground. Along with the signal system ground (S-GND), this level must be the lowest potential in the system.

 $[\]bullet$ The three power supply pins VCC-S, VCC1, and VCC2 must be shorted together externally.

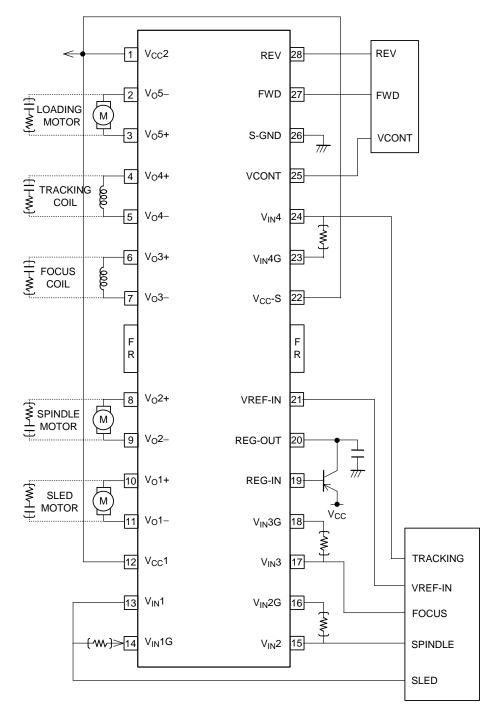
Pin Functions

Pin No.	Symbol	Pin name	Pin description	Equivalent circuit
13 14 15 16 17 18 23 24	VIN	Inputs	Inputs	V _{IN} G O V _{CC} -S
4 5 6 7 8 9 10 11	Vo	Outputs	Outputs	V _{CC} 1
2 3 25	V _O 5+ V _O 5- VCONT	V _O 5	H bridge outputs	V ₀ 5+ V ₀ 5- VCONT
27 28	FWD REV	FWD REV	H bridge inputs	Vcc2

Block Diagram



Sample Application Circuit



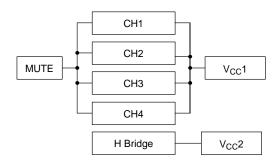
H Bridge Block

FWD	REV	V _O 5+	V _O 5–	Mode
L	L	OFF	OFF	Open *1
L	Н	Н	L	Forward
Н	L	L	Н	Reverse
Н	Н	L	L	Brake *2

Note *1: The output are in the high-impedance state in this mode

- *2: In brake mode, the sink side transistors are on (short-circuit braking). The VLO+ and VLO- levels go to a level essentially the same as the ground
- *3: VCONT (output voltage setting pin) and VLO have the following relationship: VLO = VCONT 1 V (typical)

Relationship between the MUTE pin and the power supplies (V_{CC*})



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